

**ISP814X, ISP824X, ISP844X  
ISP814, ISP824, ISP844**



# ISOCOM

## COMPONENTS

### HIGH DENSITY A.C. INPUT PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



#### APPROVALS

- UL recognised, File No. E91231  
Package Code " EE "
- 'X' SPECIFICATION APPROVALS
- VDE 0884 in 3 available lead form :-
  - STD
  - G form
  - SMD approved to CECC 00802
- ISP814 Certified to EN60950 by Nemko - Certificate No. P01102465

#### DESCRIPTION

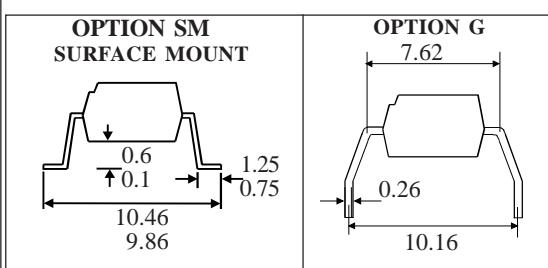
The ISP814, ISP824, ISP844 series of optically coupled isolators consist of two infrared light emitting diodes connected in inverse parallel and NPN silicon photo transistors in space efficient dual in line plastic packages.

#### FEATURES

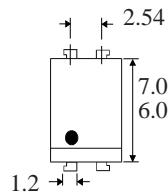
- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Isolation Voltage ( $5.3\text{kV}_{\text{RMS}}, 7.5\text{kV}_{\text{PK}}$ )
- AC or polarity insensitive input
- All electrical parameters 100% tested
- Custom electrical selections available

#### APPLICATIONS

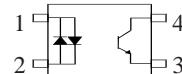
- Computer terminals
- Industrial systems controllers
- Telephone sets, Telephone exchangers
- Signal transmission between systems of different potentials and impedances



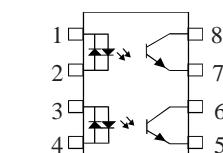
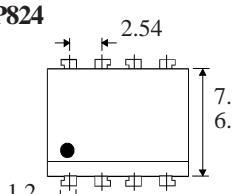
**ISP814X  
ISP814**



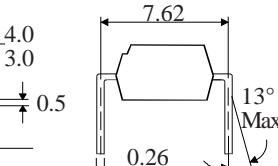
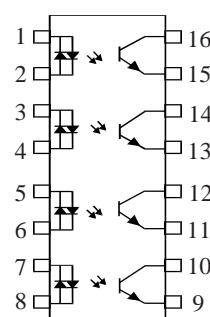
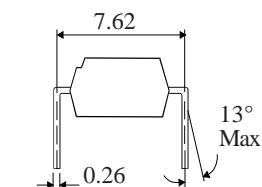
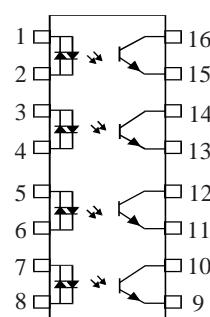
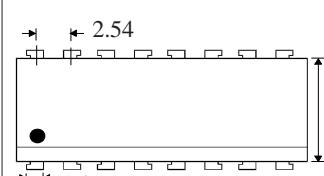
Dimensions in mm



**ISP824X  
ISP824**



**ISP844X  
ISP844**



**ABSOLUTEMAXIMUMRATINGS**  
(25°C unless otherwise specified)

Storage Temperature	-55°C to +125°C
Operating Temperature	-30°C to +100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

**INPUTDIODE**

Forward Current	±50mA
Power Dissipation	70mW

**OUTPUTTRANSISTOR**

Collector-emitter Voltage BV <sub>CEO</sub>	35V
Emitter-collector Voltage BV <sub>ECO</sub>	6V
Collector Current	50mA
Power Dissipation	150mW

**POWERDISSIPATION**

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

**ELECTRICAL CHARACTERISTICS ( T<sub>A</sub> = 25°C Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V <sub>F</sub> )		1.2	1.4	V	I <sub>F</sub> = ± 20mA
Output	Collector-emitter Breakdown (BV <sub>CEO</sub> ) ( Note 2 )	35			V	I <sub>C</sub> = 1mA
	Emitter-collector Breakdown (BV <sub>ECO</sub> )	6			V	I <sub>E</sub> = 100µA
	Collector-emitter Dark Current (I <sub>CEO</sub> )			100	nA	V <sub>CE</sub> = 20V
Coupled	Current Transfer Ratio (CTR) (Note 2) ISP814, ISP824, ISP844 ISP814A, ISP824A, ISP844A	20		300	%	± 1mA I <sub>F</sub> , 5V V <sub>CE</sub>
		50		150	%	
	Collector-emitter Saturation Voltage V <sub>CE (SAT)</sub>			0.2	V	± 20mA I <sub>F</sub> , 1mA I <sub>C</sub>
	Input to Output Isolation Voltage V <sub>ISO</sub>	5300			V <sub>RMS</sub>	See note 1
		7500			V <sub>PK</sub>	See note 1
	Input-output Isolation Resistance R <sub>ISO</sub>	5x10 <sup>10</sup>			Ω	V <sub>IO</sub> = 500V (note 1)
	Output Rise Time tr		4	18	µs	V <sub>CE</sub> = 2V ,
	Output Fall Time tf		3	18	µs	I <sub>C</sub> = 2mA, R <sub>L</sub> = 100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

